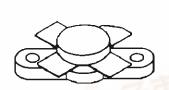


SD1274-01

RF & MICROWAVE TRANSISTORS VHF MOBILE APPLICATIONS

- COMMON EMITTER WWW.DZEG.BOM



.380 4LFL (M113)

epoxy sealed

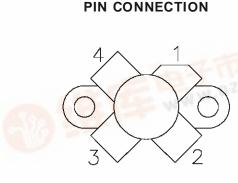
ORDER CODE SD1274-01

BRANDING

SD1274-1

DESCRIPTION

The SD1274-01 is a 13.6 V Class C epitaxial silicon NPN planar transistor designed primarily for VHF communications. The SD1274-01 utilizes an emitter ballasted die geometry to withstand severe load mismatch conditions.



- 1. Collector
- 3. Base
- 2. Emitter
- 4. Emitter

ABSOLUTE MAXIMUM RATINGS $(T_{case} = 25^{\circ}C)$

Symbol	Parameter	Value	Unit
Vсво	Collector-Base Voltage	36	V
V _{CEO}	Collector-Emitter Voltage	16	V
V _{CES}	Collector-Emitter Voltage	36	V
VEBO	Emitter-Base Voltage	4.0	V
lc lc	Device Current	8.0	А
P _{DISS}	P _{DISS} Power Dissipation		W
TJ	Junction Temperature	+200	°C
T _{STG} Storage Temperature		– 65 to +150	°C

HERMAL DATA

R _{TH(j-c)}	Junction-Case Thermal Resistance	1.2	°C/W

SD1274-01

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

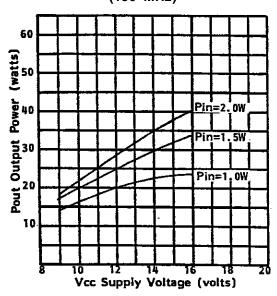
Symbol		Test Conditions	Value		Unit	
		rest conditions	Min. Typ. Max.		o i i i	
BVces	Ic = 15mA	$V_{BE} = 0mA$	36	_		V
BV _{CEO}	I _C = 50mA	$I_B = 0mA$	16	_		V
BV _{EBO}	I _E = 5mA	$I_C = 0mA$	4.0	_	_	V
I _{CBO}	V _{CB} = 15V	$I_E = 0mA$		_	5	mA
hFE	Vce = 5V	I _C = 250mA	20	_	_	_

DYNAMIC

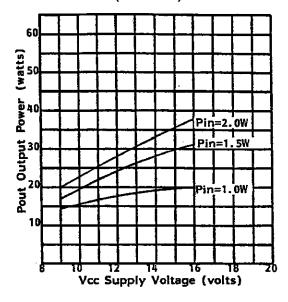
Symbol		Test Conditions			Value	Unit	
Syllibol	rest Conditions				Тур.	Max.	Oiiit
Роит	f = 160 MHz	$P_{IN} = 3.0 W$	$V_{CE} = 13.6 \text{ V}$	30	_	_	W
G _P	f = 160 MHz	$P_{IN} = 3.0 \text{ W}$	$V_{CE} = 13.6 \text{ V}$	10	_	_	dB
СОВ	f = 1 MHz	V _{CB} = 15 V		_	95	_	pF

TYPICAL PERFORMANCE

POWER OUTPUT vs SUPPLY VOLTAGE (136 MHz)

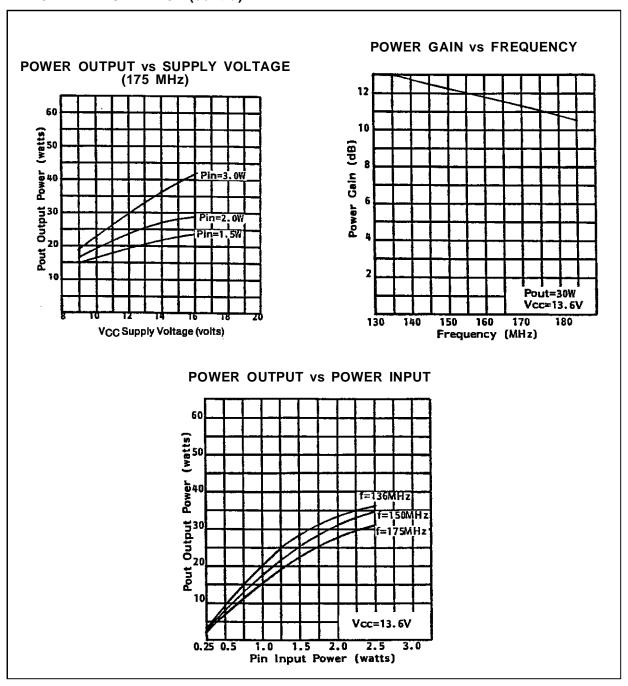


POWER OUTPUT vs SUPPLY VOLTAGE (150 MHz)



0/4

TYPICAL PERFORMANCE (cont'd)

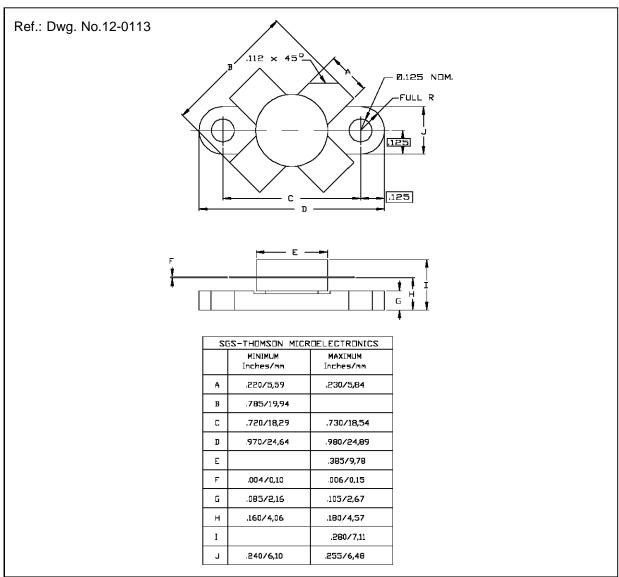


IMPEDANCE DATA

FREQ.	Z _{IN} (Ω)	Z _{CL} (Ω)
175 MHz	1.0 + j 0.4	2.3 + j 0.1

 $P_{IN} = 3.0 \text{ W}$ $V_{CE} = 12.5 \text{ V}$

PACKAGE MECHANICAL DATA



Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsability for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may results from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectonics.

© 1994 SGS-THOMSON Microelectronics - All Rights Reserved